

Question Paper

Exam Date & Time: 04-Jun-2024 (10:00 AM - 01:00 PM)



MANIPAL ACADEMY OF HIGHER EDUCATION

Manipal School of Information Sciences (MSIS), Manipal
Second Semester Master of Engineering - ME (VLSI Design / Microelectronics and VLSI Technology) Degree Examination
(Makeup Exam) - June 2024

Low Power VLSI Design [VLS 5202]

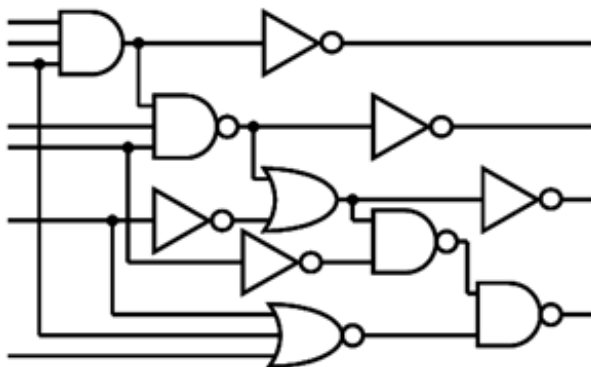
Marks: 100

Duration: 180 mins.

Tuesday, 04 June 2024

Answer all the questions.

- 1) Derive an expression for the short-circuit power dissipation component in a CMOS circuit. Analyze the effect of output load capacitance on the short-circuit current. [L4, CO-1] (10)
- 2) Explain the following techniques for leakage reduction: (3+3+4) [L2, CO-2] (10)
 - a) Multiple channel doping
 - b) Multiple body bias
 - c) Super cut-off CMOS (SCCMOS)
- 3) Explain with diagrams, the following multiple V_{th} techniques to suppress the sub-threshold leakage current: [L2, CO-2] (10)
 - Multi-threshold CMOS (MTCMOS) (5)
 - Dual threshold CMOS (5)
- 4) The following circuit is designed in a CMOS technology using low threshold transistors. Each gate has a delay of 4ps and a leakage current of 12nA. Given that a gate with high threshold transistors has a delay of 15ps and leakage of 2nA. [L3, CO-2] (10)
 - a) Optimally design the circuit with dual-threshold gates to minimize the leakage current without increasing the critical path delay. What is the percentage reduction in leakage power? (5)
 - b) What will the leakage power reduction be if a 25% increase in the critical path delay is allowed? (5)



- 5) Explain with relevant diagrams, the Voltage Scaling through Optimal Transistor Sizing approach for dynamic power reduction. [L2, CO-3] (10)
- 6) Model and explain with the help of neat diagrams, the Architecture-Driven Voltage Scaling technique by trading area for lower dynamic power through hardware duplication. [L3, CO-3] (10)
- 7) Explain the various ways of glitch reduction with relevant diagrams. [L2, CO-3] (10)
- 8) Describe the combinational and sequential clock gating methods. [L2, CO-3] (10)

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| 9) | Discuss the effects of clock latency and skew in the context of clock gating. [L2, CO-3] | (10) |
| 10) | Explain the system design issues with multi-voltage designs. [L2, CO-3] | (10) |

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